





Tools &

Software





TPS7A84

ZHCSEI2A - JANUARY 2016 - REVISED JANUARY 2016

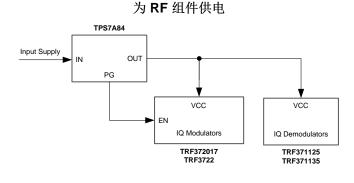
TPS7A84 高电流 (3A)、高效 (1%)、 低噪声 (4.4 µV_{RMS}) LDO 稳压器

1 特性

- 低压降: 电流为 3A 时的电压为 180mV (最大值)
- 线路、负载和温度精度为 1%(最大值)
- 输出电压噪声:
 - 4.4 µV_{RMS} (输出为 0.8V)
 - 7.7 μV_{RMS} (输出为 5.0V)
- 输入电压范围:
 - 无偏置: 1.4V 至 6.5V
 - 有偏置: 1.1V 至 6.5V
- ANY-OUT™运行:
 - 输出电压范围: 0.8V 至 3.95V
- 可调节运行:
 - 输出电压范围: 0.8V 至 5.0V
- 电源纹波抑制:
- 500kHz 时为 40dB
- 出色的负载瞬态响应
- 可调节软启动浪涌电流控制
- 开漏电源正常 (PG) 输出
- 与 47µF 或更大的陶瓷输出电容一起工作时保持稳定
- 20 引脚 3.5mm × 3.5mm 超薄型四方扁平无引线 (VQFN) 封装

2 应用

- 数字负载: 串行解串器、现场可编程门阵列 (FPGA)和数字信号处理器 (DSP)
- 仪器仪表、医疗和音频
- 高速模拟电路:
 - 压控振荡器 (VCO)、模数转换器 (ADC)、数模 转换器 (DAC) 以及低压差分信令 (LVDS)
- 成像: 互补金属氧化物半导体 (CMOS) 传感器和视频专用集成电路 (ASIC)
- 测试和测量



3 说明

TPS7A84 是一款低噪声 (4.4 μV_{RMS})、低压降 (LDO) 线性稳压器,可提供 3A 负载电流,其最高压降仅为 180mV。该器件的输出电压可通过引脚在 0.8V 至 3.95V 的范围内进行编程并可通过外部电阻分压器在 0.8V 至 5.0V 范围内进行调节。

TPS7A84 将低噪声 (4.4 μV_{RMS})、高电源抑制比 (PSRR) 和高输出电流性能相结合,非常适合为高速通 信、视频、医疗或测试和测量 等应用中的噪声敏感型 组件供电。TPS7A84 的高性能可限制电源生成的相位 噪声和时钟抖动,非常适合为高性能串行器和解串器 (SerDes)、模数转换器 (ADC)、数模转换器 (DAC) 以 及射频 (RF) 组件供电。RF 放大器尤其受益于该器件 的高性能和 5.0V 输出性能。

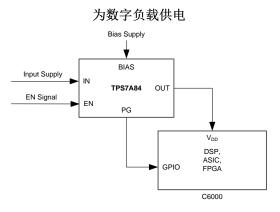
对于需要以低输入电压、低输出 (LILO) 电压运行的数 字负载 [如特定用途集成电路 (ASIC)、现场可编程门阵 列 (FPGA) 以及数字信号处理器 (DSP)], TPS7A84 优 异的精度特性(负载和温度范围内的精度为 0.75%)、远程感测、出色的瞬态性能以及软启动功能 可确保最优系统性能。

TPS7A84 的多种用途使其成为 适用于不同应用的理想 组件。。

器件信息 ⁽¹⁾	
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器件型号	封装	封装尺寸(标称值)
TPS7A84	超薄四方扁平无引线 封装 (VQFN) (20)	3.50mm x 3.50mm

(1) 如需了解所有可用封装,请见数据表末尾的可订购产品附录。







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4 修订历史记录

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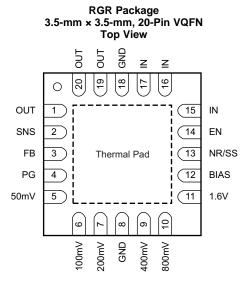
Changes from Original (January 2016) to Revision A

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5 Pin Configurations and Functions



Pin Functions

PIN					
NAME	NO.	I/O	DESCRIPTION		
50mV	5				
100mV	6		ANY-OUT voltage setting pins. Connect these pins to ground, SNS, or leave floating. Connecting these pins to ground		
200mV	7		increases the output voltage, whereas connecting these pins to SNS increases the resolution of the ANY-OUT network but decreases the range of the network; multiple pins can be simultaneously connected to GND or SNS to select the		
400mV	9		desired output voltage. Leave these pins floating (open) when not in use. See the ANY-OUT Programmable Output		
800mV	10		Voltage section for additional details.		
1.6V	11				
BIAS	12	I	S supply voltage. This pin enables the use of low-input voltage, low-output (LILO) voltage conditions (that is, $V_{IN} = V$, $V_{OUT} = 1 V$) to reduce power dissipation across the die. The use of a BIAS voltage improves dc and ac prmance for $V_{IN} \le 2.2 V$. A 10- μ F capacitor or larger must be connected between this pin and ground. If not used, pin must be left floating or tied to ground.		
EN	14	I	able pin. Driving this pin to logic high enables the device; driving this pin to logic low disables the device. If enable ctionality is not required, this pin must be connected to IN. If enable functionality is required, V_{EN} must always be high er V_{IN} is established when a BIAS supply is used. See the <i>Sequencing Requirements</i> section for more details.		
FB	3	I	Feedback pin connected to the error amplifier. Although not required, a 10-nF feed-forward capacitor from FB to OUT (as close to the device as possible) is recommended to maximize ac performance. The use of a feed-forward capacito can disrupt PG (power good) functionality. See the ANY-OUT Programmable Output Voltage and Adjustable Operation sections for more details.		
GND	8, 18	_	Ground pin. These pins must be connected to ground, the thermal pad, and each other with a low-impedance connection.		
IN	15-17	I	Input supply voltage pin. A 47-µF or larger ceramic capacitor (25 µF or greater of capacitance) from IN to ground is recommended to reduce the impedance of the input supply. Place the input capacitor as close to the input as possible. See the <i>Input and Output Capacitor Requirements</i> section for more details.		
NR/SS	13	_	Noise-reduction and soft-start pin. Connecting an external capacitor between this pin and ground reduces reference voltage noise and also enables the soft-start function. Although not required, a 10-nF or larger capacitor is recommended to be connected from NR/SS to GND (as close to the pin as possible) to maximize ac performance. See the <i>Noise-Reduction and Soft-Start Capacitor</i> section for more details.		
OUT	1, 19, 20	0	Regulated output pin. A 47-µF or larger ceramic capacitor (25 µF or greater of capacitance) from OUT to ground is required for stability and must be placed as close to the output as possible. Minimize the impedance from the OUT pin to the load. See the <i>Input and Output Capacitor Requirements</i> section for more details.		
PG	4	0	Active-high, power-good pin. An open-drain output indicates when the output voltage reaches 89.3% of the target. The use of a feed-forward capacitor can disrupt PG (power good) functionality. See the <i>Power-Good Function</i> section for more details.		
SNS	2	I	Output voltage sense input pin. This pin connects the internal R ₁ resistor to the output. Connect this pin to the load side of the output trace only if the ANY-OUT feature is used. If the ANY-OUT feature is not used, leave this pin floating. See the ANY-OUT Programmable Output Voltage and Adjustable Operation sections for more details.		
Thermal pad		—	Connect the thermal pad to a large-area ground plane. The thermal pad is internally connected to GND.		

6 Specifications

6.1 Absolute Maximum Ratings

over junction temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage	IN, BIAS, PG, EN	-0.3	7.0	V
	IN, BIAS, PG, EN (5% duty cycle, pulse duration = 200 μ s)	-0.3	7.5	V
	SNS, OUT	-0.3	$V_{IN} + 0.3^{(2)}$	V
	NR/SS, FB	-0.3	3.6	V
	50mV, 100mV, 200mV, 400mV, 800mV, 1.6V	-0.3	V _{OUT} + 0.3	V
Current	OUT	Interna	ally limited	А
Current	PG (sink current into device)		5	mA
Operating junction temperature, T _J		-55	150	°C
Storage temperature, T _{stg}		-55	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The absolute maximum rating is V_{IN} + 0.3 V or 7.0 V, whichever is smaller.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD) Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V	
	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over junction temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{IN}	Input supply voltage range	1.1		6.5	V
V _{BIAS}	Bias supply voltage range ⁽¹⁾	3.0		6.5	V
V _{OUT}	Output voltage range ⁽²⁾	0.8		5	V
V _{EN}	Enable voltage range	0		V _{IN}	V
I _{OUT}	Output current	0		3	А
C _{IN}	Input capacitor	10	47		μF
C _{OUT}	Output capacitor	47	47 10 10 ⁽³⁾		μF
R _{PG}	Power-good pullup resistance	10		100	kΩ
C _{NR/SS}	NR/SS capacitor		10		nF
C _{FF}	Feed-forward capacitor		10		nF
R ₁	Top resistor value in feedback network for adjustable operation		12.1 ⁽⁴⁾		kΩ
R ₂	Bottom resistor value in feedback network for adjustable operation			160 ⁽⁵⁾	kΩ
TJ	Operating junction temperature	-40		125	°C

(1) BIAS supply is required when the V_{IN} supply is below 1.4 V. Conversely, no BIAS supply is required when the V_{IN} supply is higher than or equal to 1.4 V. A BIAS supply helps improve dc and ac performance for V_{IN} \leq 2.2 V.

2) This output voltage range does not include device accuracy or accuracy of the feedback resistors.

(3) The recommended output capacitors are selected to optimize PSRR for the frequency range of 400 kHz to 700 kHz. This frequency range is a typical value for dc-dc supplies.

(4) The 12.1-k Ω resistor is selected to optimize PSRR and noise by matching the internal R₁ value.

(5) The upper limit for the R₂ resistor is to ensure accuracy by making the current through the feedback network much larger than the leakage current into the feedback node.

6.4 Thermal Information

		TPS7A84	
	THERMAL METRIC ⁽¹⁾	RGR (VQFN)	UNIT
		20 PINS	
$R_{ extsf{ heta}JA}$	Junction-to-ambient thermal resistance	35.4	°C/W
R _{0JC(top)}	Junction-to-case (top) thermal resistance	47.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	12.3	°C/W
ΨJT	Junction-to-top characterization parameter	0.5	°C/W
Ψ _{JB}	Junction-to-board characterization parameter	12.4	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	1.0	°C/W

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.

6.5 Electrical Characteristics

Over operating junction temperature range ($T_J = -40^{\circ}C$ to $+125^{\circ}C$), $V_{IN} = 1.4$ V or $V_{IN} = V_{OUT(nom)} + 0.4$ V (whichever is greater), $V_{BIAS} =$ open, $V_{OUT(nom)} = 0.8$ V⁽¹⁾, OUT connected to 50 Ω to GND⁽²⁾, $V_{EN} = 1.1$ V, $C_{IN} = 10$ μ F, $C_{OUT} = 47$ μ F, $C_{NR/SS}$ without C_{FF} , and PG pin pulled up to V_{IN} with 100 k Ω , unless otherwise noted. Typical values are at $T_J = 25^{\circ}C$.

PARAMETER			TEST CONDITIONS	MIN	TYP	MAX	UNIT	
V _{IN}	Input supply voltag	e range ⁽³⁾		1.1		6.5	V	
V _{BIAS}	Bias supply voltage	e range ⁽³⁾	V _{IN} = 1.1 V	3.0		6.5	V	
V _{FB}	Feedback voltage				0.8		V	
V _{NR/SS}	NR/SS pin voltage				0.8		V	
V _{UVLO1(IN)}	Input supply UVLO	with BIAS	V_{IN} rising with $V_{BIAS} = 3.0 \text{ V}$		1.02	1.085	V	
V _{HYS1(IN)}	V _{UVLO1(IN)} hysteresis		V _{BIAS} = 3.0 V		320		mV	
V _{UVLO2(IN)}	Input supply UVLO	without BIAS	V _{IN} rising		1.31	1.39	V	
V _{HYS2(IN)}	V _{UVLO2(IN)} hysteres	is			253		mV	
V _{UVLO(BIAS)}	Bias supply UVLO		V_{BIAS} rising, V_{IN} = 1.1 V		2.83	2.9	V	
V _{HYS(BIAS)}	V _{UVLO(BIAS)} hystere	sis	V _{IN} = 1.1 V		290		mV	
	Output voltage	2	Using the ANY-OUT pins	0.8 - 1.0%		3.95 + 1.0%	.,	
			Range	Using external resistors ⁽⁴⁾	0.8 - 1.0%		5.0 + 1.0%	V
V _{OUT}		Accuracy ⁽⁴⁾⁽⁵⁾	$0.8 \text{ V} \le \text{V}_{\text{OUT}} \le 5 \text{ V}, 5 \text{ mA} \le \text{I}_{\text{OUT}} \le 3 \text{ A}, \text{ over } \text{V}_{\text{IN}}$	-1.0%		1.0%		
		Accuracy with BIAS	V_{IN} = 1.1 V, 5 mA $\leq I_{OUT} \leq$ 3 A, 3.0 V $\leq V_{BIAS} \leq$ 6.5 V	-0.75%		0.75%		
ΔV _{OUT} / ΔV _{IN}	Line regulation		$I_{OUT} = 5 \text{ mA}, 1.4 \text{ V} \le V_{IN} \le 6.5 \text{ V}$		0.0035		mV/V	
Δν _{ουτ} /			5 mA \leq I _{OUT} \leq 3 A, 3.0 V \leq V _{BIAS} \leq 6.5 V, V _{IN} = 1.1 V		0.07		mV/A	
ΔI_{OUT}	Load regulation		$5 \text{ mA} \le I_{\text{OUT}} \le 3 \text{ A}$		0.08			
			$5 \text{ mA} \le I_{\text{OUT}} \le 3 \text{ A}, \text{ V}_{\text{OUT}} = 5.0 \text{ V}$		0.4			
			$V_{IN} = 1.4 \text{ V}, I_{OUT} = 3 \text{ A}, V_{FB} = 0.8 \text{ V} - 3\%$		156	250		
V _{DO}	Dropout voltage		$V_{IN} = 5.4 \text{ V}, I_{OUT} = 3 \text{ A}, V_{FB} = 0.8 \text{ V} - 3\%$		220	340	mV	
•DO	Dropour voitage		$V_{IN} = 1.1 \text{ V}, V_{BIAS} = 5.0 \text{ V},$ $I_{OUT} = 3 \text{ A}, V_{FB} = 0.8 \text{ V} - 3\%$		110	180	IIIV	
I _{LIM}	Output current limit		V_{OUT} forced at 0.9 × $V_{OUT(nom)}$, $V_{IN} = V_{OUT(nom)} + 0.4 V$	3.7	4.2	4.7	А	
I _{SC}	Short-circuit curren	nt limit	$R_{LOAD} = 20 \text{ m}\Omega$		1.0		А	
			V _{IN} = 6.5 V, I _{OUT} = 5 mA		2.8	4	0	
I _{GND}	GND pin current		V _{IN} = 1.4 V, I _{OUT} = 3 A		4.2	5.5	mA	
			Shutdown, PG = open, V_{IN} = 6.5 V, V_{EN} = 0.5 V			25	μA	

(1) V_{OUT(nom)} is the calculated V_{OUT} target value from the ANY-OUT in a fixed configuration. In an adjustable configuration, V_{OUT(nom)} is the expected V_{OUT} value set by the external feedback resistors.

(2) This 50- Ω load is disconnected when the test conditions specify an I_{OUT} value.

(3) BIAS supply is required when the V_{IN} supply is below 1.4 V. Conversely, no BIAS supply is required when the V_{IN} supply is higher than or equal to 1.4 V. A BIAS supply helps improve dc and ac performance for V_{IN} ≤ 2.2 V.

(4) When the device is connected to external feedback resistors at the FB pin, external resistor tolerances are not included.

(5) The device is not tested under conditions where $V_{IN} > V_{OUT} + 1.7$ V and $I_{OUT} = 3$ A, because the power dissipation is higher than the maximum rating of the package.

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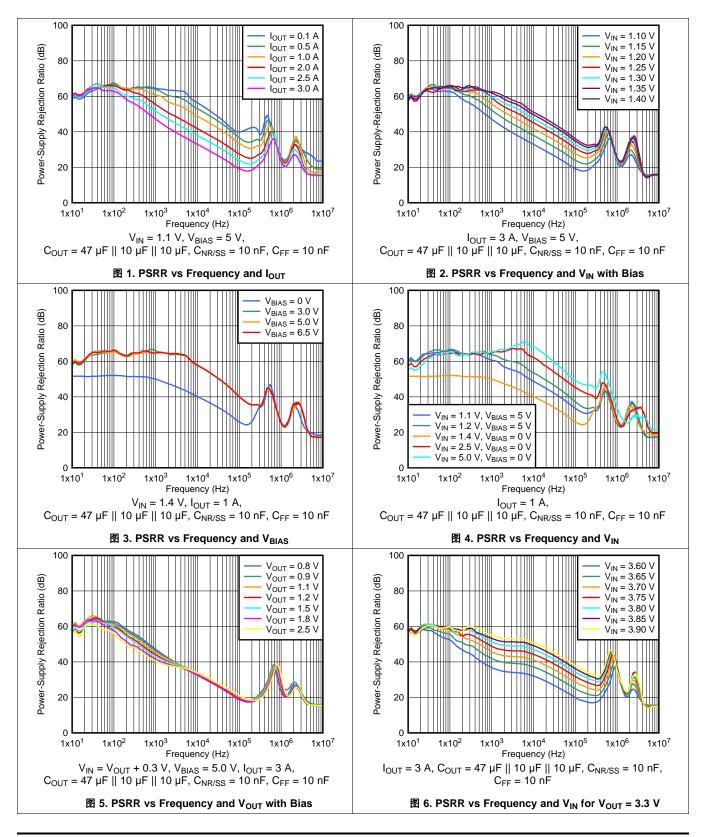
Electrical Characteristics (continued)

Over operating junction temperature range (T_J = -40°C to +125°C), V_{IN} = 1.4 V or V_{IN} = V_{OUT(nom)} + 0.4 V (whichever is greater), V_{BIAS} = open, V_{OUT(nom)} = 0.8 V⁽¹⁾, OUT connected to 50 Ω to GND⁽²⁾, V_{EN} = 1.1 V, C_{IN} = 10 μ F, C_{OUT} = 47 μ F, C_{NR/SS} without C_{FF}, and PG pin pulled up to V_{IN} with 100 k Ω , unless otherwise noted. Typical values are at T_J = 25°C.

PARAMETER		PARAMETER TEST CONDITIONS		MIN	TYP	MAX	UNIT
I _{EN}	EN pin current	V_{IN} = 6.5 V, V_{EN} = 0 V and 6.	V_{IN} = 6.5 V, V_{EN} = 0 V and 6.5 V			0.1	μA
I _{BIAS}	BIAS pin current	$V_{IN} = 1.1 \text{ V}, V_{BIAS} = 6.5 \text{ V}, V_{OUT(nom)} = 0.8 \text{ V}, I_{OUT} = 3 \text{ A}$			2.3	3.5	mA
V _{IL(EN)}	EN pin high-level input voltage (enable device)			0		0.5	V
V _{IH(EN)}	EN pin low-level input voltage (disable device)			1.1		6.5	V
V _{IT(PG)}	PG pin threshold	For falling V _{OUT}		82% × V _{OUT}	88.3% × V _{OUT}	93% × V _{OUT}	V
V _{HYS(PG)}	PG pin hysteresis	For rising V _{OUT}			$1\% \times V_{OUT}$		V
V _{OL(PG)}	PG pin low-level output voltage	$V_{OUT} < V_{IT(PG)}, I_{PG} = -1 \text{ mA}$ (current into device)				0.4	V
I _{lkg(PG)}	PG pin leakage current	$V_{OUT} > V_{IT(PG)}, V_{PG} = 6.5 V$				1	μA
I _{NR/SS}	NR/SS pin charging current	$V_{NR/SS} = GND, V_{IN} = 6.5 V$	$V_{NR/SS} = GND, V_{IN} = 6.5 V$		6.2	9.0	μA
I _{FB}	FB pin leakage current	V _{IN} = 6.5 V		-100		100	nA
	Power-supply ripple rejection		f = 10 kHz, V _{OUT} = 0.8 V, V _{BIAS} = 5.0 V		42		
PSRR		$V_{IN} - V_{OUT} = 0.4 V,$ $I_{OUT} = 3 A, C_{NR/SS} = 100 nF,$ $C_{FF} = 10 nF, C_{OUT} =$	f = 500 kHz, V _{OUT} = 0.8 V, V _{BIAS} = 5.0 V		39		dB
		47 μF 10 μF 10 μF	f = 10 kHz, V _{OUT} = 5.0 V		40		
			f = 500 kHz, V _{OUT} = 5.0 V		25		
V _n	Output noise voltage	$\begin{array}{l} BW = 10 \; Hz \; to \; 100 \; kHz, \; V_{IN} \\ V_{OUT} = 0.8 \; V, \; V_{BIAS} = 5.0 \; V, \; I \\ C_{NR/SS} = 100 \; nF, \; C_{FF} = 10 \; nF \\ C_{OUT} = 47 \; \mu F \; \ \; 10 \; \mu F \; \ \; 10 \; \mu \end{array}$	_{OUT} = 3 A, =,		4.4		μV _{RMS}
		$\begin{array}{l} BW = 10 \text{ Hz to } 100 \text{ kHz}, \\ V_{OUT} = 5.0 \text{ V}, I_{OUT} = 3 \text{ A}, C_{NF} \\ C_{FF} = 10 \text{ nF}, C_{OUT} = 47 \mu\text{F} \end{array}$			7.7		
т.	Thermal shutdown temperature	Shutdown, temperature incre	asing		160		°C
T _{sd}		Reset, temperature decreasing	ng		140		
TJ	Operating junction temperature			-40		125	°C

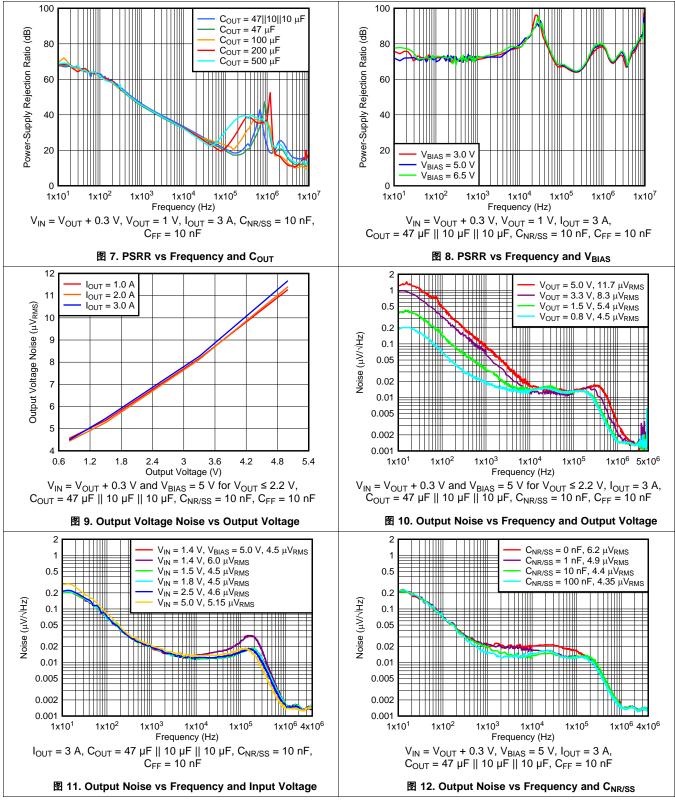


6.6 Typical Characteristics



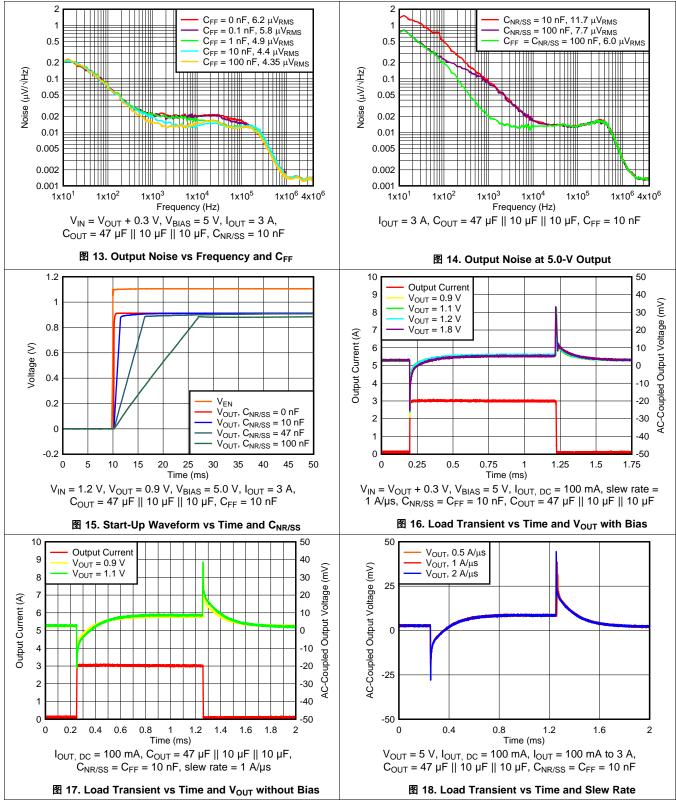


Typical Characteristics (接下页)





Typical Characteristics (接下页)





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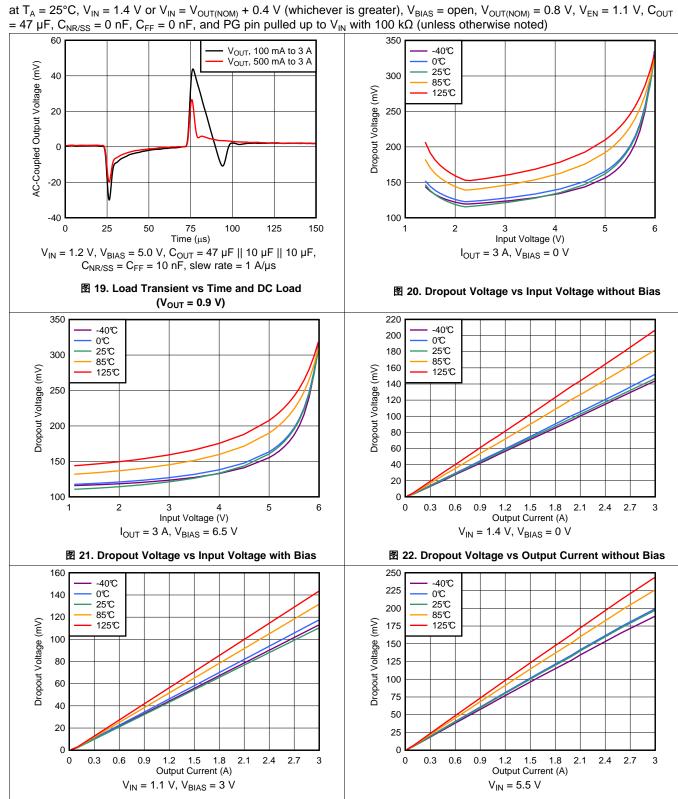
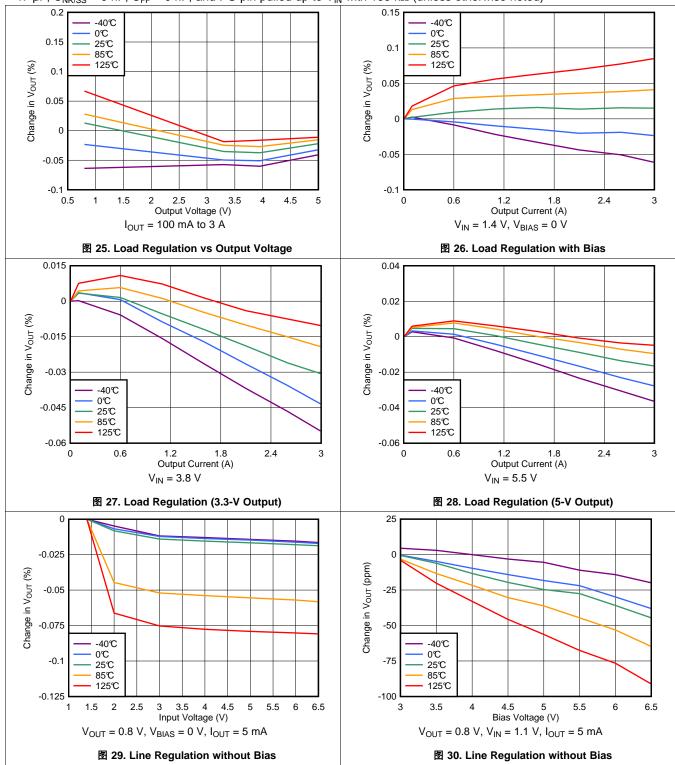


图 24. Dropout Voltage vs Output Current (High VIN)

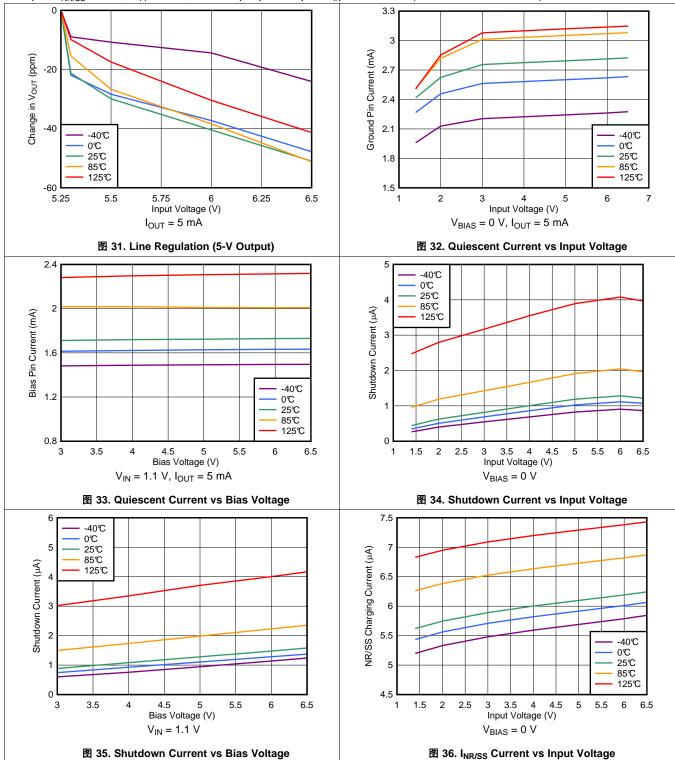


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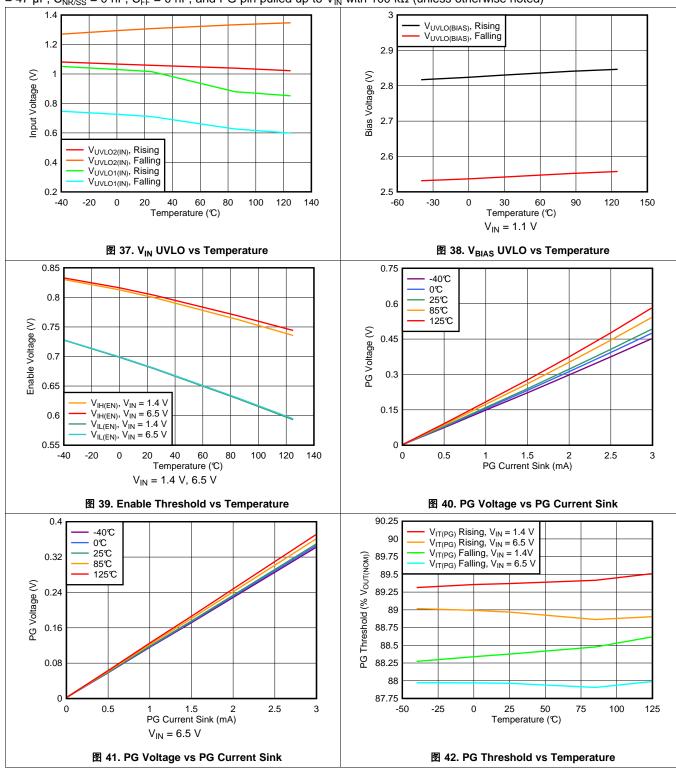


Typical Characteristics (接下页)





Typical Characteristics (接下页)





7 Detailed Description

7.1 Overview

The TPS7A84 is a high-current (3 A), low-noise (4.4 μV_{RMS}), high accuracy (1%) low-dropout linear voltage regulator (LDO). These features make the device a robust solution to solve many challenging problems in generating a clean, accurate power supply.

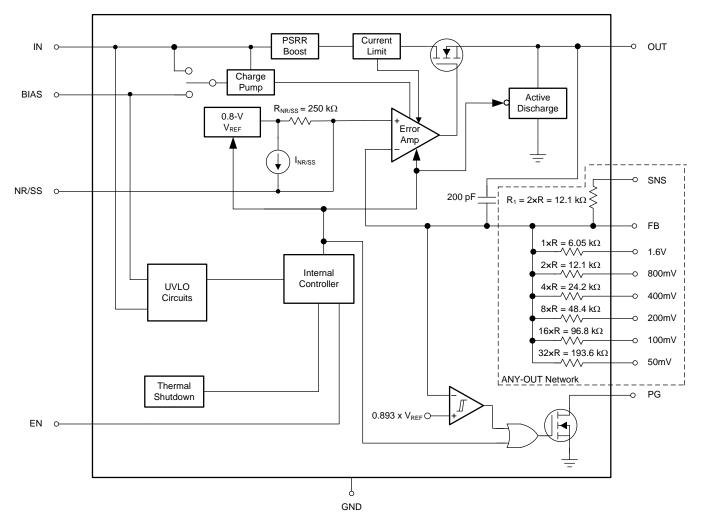
The TPS7A84 has several features that make the device useful in a variety of applications. As detailed in the *Functional Block Diagram* section, these features include:

- Low-noise, high-PSRR output
- ANY-OUT resistor network
- Optional bias rail
- Power-good output
- Programmable soft-start
- Foldback current limit
- Enable circuitry
- Active discharge
- Thermal protection

Overall, these features make the TPS7A84 the component of choice because of its versatility and ability to generate a supply for most applications.



7.2 Functional Block Diagram



NOTE: For the ANY-OUT network, the ratios between the values are highly accurate as a result of matching, but the actual resistance can vary significantly from the numbers listed.

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7.3 Feature Description

7.3.1 Low-Noise, High-PSRR Output

The TPS7A84 includes a low-noise reference and error amplifier ensuring minimal noise during operation. The NR/SS capacitor ($C_{NR/SS}$) and feed-forward capacitor (C_{FF}) are the easiest way to reduce device noise. $C_{NR/SS}$ filters the noise from the reference and C_{FF} filters the noise from the error amplifier. The noise contribution from the charge pump is minimal. The overall noise of the system at low output voltages can be reduced by using a bias rail because this rail provides more headroom for internal circuitry.

The high power-supply rejection ratio (PSRR) of the TPS7A84 ensures minimal coupling of input supply noise to the output. The PSRR performance is primarily results from a high-bandwidth, high-gain error amplifier and an innovative circuit to boost the PSRR between 200 kHz and 1 MHz.

The combination of a low noise-floor and high PSRR ensure that the device provides a clean supply to the application; see the *Optimizing Noise and PSRR* section for more information on optimizing the noise and PSRR performance.

7.3.2 Integrated Resistance Network (ANY-OUT)

An internal feedback resistance network is provided, allowing the TPS7A84 output voltage to be programmed easily between 0.8 V to 3.95 V with a 50-mV step by tying the ANY-OUT pins to ground. Tying the ANY-OUT pins to SNS increases the resolution but limits the range of the output voltage because the effective value of R_1 is decreased. Use the ANY-OUT network for excellent accuracy across output voltage and temperature; see the *Application and Implementation* section for more details.

7.3.3 Bias Rail

The device features a bias rail to enable low-input voltage, low-output (LILO) voltage operation by providing power to the internal circuitry of the device. The bias rail is required for operation with $V_{IN} < 1.4$ V, and is recommended for $V_{IN} \leq 2.2$ V to improve dc and ac performance. An internal power-MUX supplies the greater of either the input voltage or the bias voltage to an internal charge pump to power the internal circuitry. Using the bias rail does constitute some sequencing requirements that are detailed in the *Sequencing Requirements* section.

7.3.4 Power-Good Function

The power-good circuit monitors the voltage at the feedback pin to indicate the status of the output voltage. When the feedback pin voltage falls below the PG threshold voltage ($V_{IT(PG)} + V_{HYS(PG)}$, typically 89.3%), the PG pin open-drain output engages and pulls the PG pin close to GND. When the feedback voltage exceeds the $V_{IT(PG)}$ threshold by an amount greater than $V_{HYS(PG)}$ (typically 91.3%), the PG pin becomes high impedance. By connecting a pullup resistor to an external supply, any downstream device can receive power-good as a logic signal that can be used for sequencing. Make sure that the external pullup supply voltage results in a valid logic signal for the receiving device or devices. Using a pullup resistor from 10 k Ω to 100 k Ω is recommended. Using an external voltage detector device such as the TPS3702 is also recommended in applications where more accurate voltage monitoring or overvoltage monitoring is required.

The use of a feed-forward capacitor (C_{FF}) can cause glitches on start-up, and the power-good circuit may not function normally below the minimum input supply range. For more details on the use of the power-good circuitry, see the *Power-Good Operation* section.

7.3.5 Programmable Soft-Start

Soft-start refers to the ramp-up time of the output voltage during LDO turn-on after EN and UVLO exceed the respective threshold voltage. The noise-reduction capacitor ($C_{NR/SS}$) serves a dual purpose of both governing output noise reduction and programming the soft-start ramp time during turn-on. The start-up ramp is monotonic and linear in most conditions, however there is a small set of conditions that cause a small initial jump in output voltage. See the *Application and Implementation* section on implementing a soft-start.



Feature Description (接下页)

7.3.6 Internal Current Limit (I_{LIM})

The internal current limit circuit is used to protect the LDO against high-load current faults or shorting events. During a current-limit event, the LDO sources constant current; therefore, the output voltage falls with decreased load impedance. Thermal shutdown can activate during a current limit event because of the high power dissipation typically found in these conditions. To ensure proper operation of the current limit, minimize the inductances to the input and load. Continuous operation in current limit is not recommended.

The foldback current limit crosses 0 A when $V_{OUT} < 0$ V and prevents the device from turning on into a negatively-biased output. See the *Negative Biased Output* section on additional ways to ensure start-up when the TPS7A84 output is pulled below ground.

7.3.7 Enable

The enable pin for the TPS7A84 is active high. The output of the TPS7A84 is turned on when the enable pin voltage is greater than its rising voltage threshold (1.1 V, max), and the output of the TPS7A84 is turned off when the enable pin voltage is less than its falling voltage threshold (0.5 V, min). A voltage less than 0.5 V on the enable pin disables all internal circuits. At the next turn-on this voltage ensures a normal start-up waveform with in-rush control, provided there is enough time to discharge the output capacitance.

When the enable functionality is not desired, EN must be tied to V_{IN} . However, when the enable functionality is desired, the enable voltage must come after V_{IN} is above $V_{UVLO1(IN)}$ when a BIAS rail is used. See the *Application and Implementation* section for further details.

7.3.8 Active Discharge Circuit

The TPS7A84 has an internal pulldown MOSFET that connects a resistance of several hundred ohms to ground when the device is disabled to actively discharge the output voltage when the device is disabled.

Do not rely on the active discharge circuit for discharging a large amount of output capacitance after the input supply has collapsed because reverse current can possibly flow from the output to the input. This reverse current flow can cause damage to the device. Limit reverse current to no more than 5% of the device rated current for a short period of time.

7.3.9 Undervoltage Lockout (UVLO)

The undervoltage lockout (UVLO) circuit monitors the input and bias voltage (V_{IN} and V_{BIAS} , respectively) to prevent the device from turning on before V_{IN} and V_{BIAS} rise above the lockout voltage. The UVLO circuit also disables the output of the device when V_{IN} or V_{BIAS} fall below the lockout voltage. The UVLO circuit responds quickly to glitches on V_{IN} or V_{BIAS} and attempts to disable the output of the device if either of these rails collapse. As a result of the fast response time of the input supply UVLO circuit, fast and short line transients well below the input supply UVLO falling threshold can cause momentary glitches when asserted or when recovered from the transient. See the *Application and Implementation* section for more details.

7.3.10 Thermal Protection

The TPS7A84 contains a thermal shutdown protection circuit to disable the device when thermal junction temperature (T_J) of the main pass-FET exceeds 160°C (typical). Thermal shutdown hysteresis assures that the LDO resets again (turns on) when the temperature falls to 140°C (typical). The thermal time-constant of the semiconductor die is fairly short, and thus the device cycles on and off when thermal shutdown is reached until the power dissipation is reduced.

For reliable operation, limit the junction temperature to a maximum of 125°C. Operation above 125°C can cause the device to exceed its operational specifications. Although the internal protection circuitry of the TPS7A84 is designed to protect against thermal overload conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the TPS7A84 into thermal shutdown or above a junction temperature of 125°C reduces long-term reliability.



7.4 Device Functional Modes

7.4.1 Operation with 1.1 V \leq V_{IN} < 1.4 V

The TPS7A84 requires a bias voltage on the BIAS pin greater than or equal to 3.0 V if the high-current input supply voltage is between 1.1 V to 1.4 V. The bias voltage pin consumes 2.3 mA, nominally.

7.4.2 Operation with 1.4 V \leq V_{IN} \leq 6.5 V

If the input voltage is equal to or exceeds 1.4 V, no BIAS voltage is required. The TPS7A84 is powered from either the input supply or the BIAS supply, whichever is greater. For higher performance, a BIAS rail is recommended for $V_{IN} \leq 2.2$ V.

7.4.3 Shutdown

Shutting down the device reduces the ground current of the device to a maximum of 25 µA.



8 Application and Implementation

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Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TPS7A84 is a linear voltage regulator with an input range of 1.1 V to 6.5 V and an output voltage range of 0.8 V to 5.0 V with a 1% accuracy and a 3-A maximum output current. The TPS7A84 has an integrated charge pump for ease of use and an external bias rail to allow for the lowest dropout across the entire output voltage range.

8.1.1 Recommended Capacitor Types

The TPS7A84 is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input, output, and noise-reduction pin (NR, pin 13). Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and COG-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, ceramic capacitance varies with operating voltage and temperature. As a rule of thumb, derate ceramic capacitors by at least 50%. The input and output capacitors recommended herein account for a capacitance derating of approximately 50%, but at high V_{IN} and V_{OUT} conditions (that is, $V_{IN} = 5.5$ V to $V_{OUT} = 5.0$ V) the derating can be greater than 50% and must be taken into consideration.

8.1.2 Input and Output Capacitor Requirements (C_{IN} and C_{OUT})

The TPS7A84 is designed and characterized for operation with ceramic capacitors of 47 μ F or greater (22 μ F or greater of capacitance) at the output and 10 μ F or greater (5 μ F or greater of capacitance) at the input. Using at least a 47- μ F capacitor is highly recommended at the input to minimize input impedance. Place the input and output capacitors as near as practical to the respective input and output pins to minimize trace parasitics. If the trace inductance from the input supply to the TPS7A84 is high, a fast current transient can cause V_{IN} to ring above the absolute maximum voltage rating and damage the device. This situation can be mitigated by additional input capacitors to dampen the ringing and to keep it below the device absolute maximum ratings.

A combination of multiple output capacitors boosts the high-frequency PSRR, as illustrated in several of the PSRR curves. The combination of one 0805-sized, 47- μ F ceramic capacitor in parallel with two 0805-sized, 10- μ F ceramic capacitors with a sufficient voltage rating in conjunction with the PSRR boost circuit optimizes PSRR for the frequency range of 400 kHz to 700 kHz, a typical range for dc-dc supply switching frequency. This 47- μ F || 10- μ F || 10- μ F || 10- μ F combination also ensures that at high input voltage and high output voltage configurations, the minimum effective capacitance is met. Many 0805-sized, 47- μ F ceramic capacitors ensures that the capacitance is at or above 22 μ F.

8.1.3 Noise-Reduction and Soft-Start Capacitor (C_{NR/SS})

The TPS7A84 features a programmable, monotonic, voltage-controlled soft-start that is set with an external capacitor ($C_{NR/SS}$). The use of an external $C_{NR/SS}$ is highly recommended, especially to minimize in-rush current into the output capacitors. This soft-start eliminates power-up initialization problems when powering field-programmable gate arrays (FPGAs), digital signal processors (DSPs), or other processors. The controlled voltage ramp of the output also reduces peak in-rush current during start-up, minimizing start-up transients to the input power bus.

Application Information (接下页)

To achieve a monotonic start-up, the TPS7A84 error amplifier tracks the voltage ramp of the external soft-start capacitor until the voltage approaches the internal reference. The soft-start ramp time depends on the soft-start charging current ($I_{NR/SS}$), the soft-start capacitance ($C_{NR/SS}$), and the internal reference ($V_{NR/SS}$). Soft-start ramp time can be calculated with 公式 1:

 $t_{SS} = (V_{NR/SS} \times C_{NR/SS}) / I_{NR/SS}$

Note that I_{NR/SS} is provided in the *Electrical Characteristics* table and has a typical value of 6.2 µA.

The noise-reduction capacitor, in conjunction with the noise-reduction resistor, forms a low-pass filter (LPF) that filters out the noise from the reference before being gained up with the error amplifier, thereby reducing the device noise floor. The LPF is a single-pole filter and the cutoff frequency can be calculated with $\Delta \pm 2$. The typical value of R_{NR} is 250 k Ω . Increasing the C_{NR/SS} capacitor has a greater affect because the output voltage increases when the noise from the reference is gained up even more at higher output voltages. For low-noise applications, a 10-nF to 1-µF C_{NR/SS} is recommended.

 $f_{cutoff} = 1/(2 \times \pi \times R_{NR} \times C_{NR/SS})$

8.1.4 Feed-Forward Capacitor (C_{FF})

Although a feed-forward capacitor (C_{FF}) from the FB pin to the OUT pin is not required to achieve stability, a 10-nF external feed-forward capacitor optimizes the transient, noise, and PSRR performance. A higher capacitance C_{FF} can be used; however, the start-up time is longer and the power-good signal can incorrectly indicate that the output voltage is settled. For a detailed description, see application report *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator*, SBVA042.

8.1.5 Optimizing Noise and PSRR

The ultra-low noise floor and PSRR of the device can be improved by careful selection of:

- C_{NR/SS} for the low-frequency range
- C_{FF} in the mid-band frequency range
- C_{OUT} for the high-frequency range
- V_{IN} V_{OUT} for all frequencies, and
- V_{BIAS} at lower input voltages

A larger noise-reduction capacitor improves low-frequency PSRR by filtering any noise coupling from the input into the reference. The feed-forward capacitor can be optimized to place a pole-zero pair near the edge of the loop bandwidth and push out the loop bandwidth, thus improving mid-band PSRR. Larger output capacitors and various output capacitors can be used to improve high-frequency PSRR.

A higher input voltage improves the PSRR by giving the device more headroom to respond to noise on the input; see 2. A bias rail also improves the PSRR at lower input voltages because greater headroom is provided for the internal circuits.

The noise-reduction capacitor filters out low-frequency noise from the reference and the feed-forward capacitor reduces output voltage noise by filtering out the mid-band frequency noise. However, a large feed-forward capacitor can create some new issues that are discussed in application report *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator*, SBVA042.

Note that a large output capacitor reduces high-frequency output voltage noise. Additionally, a bias rail or higher input voltage improves the noise because greater headroom is provided for the internal circuits.



(2)

(1)



Application Information (接下页)

 $\frac{1}{2}$ 1 lists the output voltage noise for the 10-Hz to 100-kHz band at a 5.0-V output for a variety of conditions with an input voltage of 5.4 V, an R₁ of 12.1 kΩ, and a load current of 3 A. The 5.0-V output is chosen because this output is the worst-case condition for output voltage noise.

OUTPUT VOLTAGE NOISE (µV _{RMS})	C _{NR/SS} (nF)	C _{FF} (nF)	С _{оит} (µF)
11.7	10	10	47 10 10
7.7	100	10	47 10 10
6	100	100	47 10 10
7.4	100	10	1000
5.8	100	100	1000

表 1. Output Noise Voltage at a 5.0-V Output

8.1.6 Soft-Start and In-Rush Current

Soft-start refers to the ramp-up characteristic of the output voltage during LDO turn-on after EN and UVLO achieve threshold voltage. The noise-reduction capacitor serves a dual purpose of both governing output noise reduction and programming the soft-start ramp during turn-on.

In-rush current is defined as the current into the LDO at the IN pin during start-up. In-rush current then consists primarily of the sum of load current and the current used to charge the output capacitor. This current is difficult to measure because the input capacitor must be removed, which is not recommended. However, this soft-start current can be estimated by $\Delta \vec{x}$ 3:

$$I_{\text{OUT}(t)} = \left[\frac{C_{\text{OUT}} \times dV_{\text{OUT}}(t)}{dt}\right] + \left[\frac{V_{\text{OUT}}(t)}{R_{\text{LOAD}}}\right]$$

where:

- V_{OUT}(t) is the instantaneous output voltage of the turn-on ramp
- dV_{OUT}(t) / dt is the slope of the V_{OUT} ramp
- R_{LOAD} is the resistive load impedance

8.1.7 ANY-OUT Programmable Output Voltage

The TPS7A84 can use either external resistors or the internally-matched ANY-OUT feedback resistor network to set output voltage. The ANY-OUT resistors are accessible via pin 2 and pins 5 to 11 and are used to program the regulated output voltage. Each pin is can be connected to ground (active) or left open (floating), or connected to SNS. ANY-OUT programming is set by $\Delta \pm 4$ as the sum of the internal reference voltage (V_{NR/SS} = 0.8 V) plus the accumulated sum of the respective voltages assigned to each active pin; that is, 50mV (pin 5), 100mV (pin 6), 200mV (pin 7), 400mV (pin 9), 800mV (pin 10), or 1.6V (pin 11). ± 2 summarizes these voltage values associated with each active pin setting for reference. By leaving all program pins open or floating, the output is thereby programmed to the minimum possible output voltage equal to V_{FB}.

 $V_{OUT} = V_{REF} + (\Sigma ANY-OUT Pins to Ground)$

(4)

(3)

ANY-OUT PROGRAM PINS (Active Low)	ADDITIVE OUTPUT VOLTAGE LEVEL
Pin 5 (50mV)	50 mV
Pin 6 (100mV)	100 mV
Pin 7 (200mV)	200 mV
Pin 9 (400mV)	400 mV
Pin 10 (800mV)	800 mV
Pin 11 (1.6V)	1.6 V

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表 3 provides a full list of target output voltages and corresponding pin settings when the ANY-OUT pins are only tied to ground or left floating. The voltage setting pins have a binary weight; therefore, the output voltage can be programmed to any value from 0.8 V to 3.95 V in 50-mV steps when tying these pins to ground. There are several alternative ways to set the output voltage. The program pins can be driven using external general-purpose input/output pins (GPIOs), manually connected using 0- Ω resistors (or left open), or hardwired by the given layout of the printed circuit board (PCB) to set the ANY-OUT voltage. As with the adjustable operation, the output voltage is set according to 公式 5 except that R₁ and R₂ are internally integrated and matched for higher accuracy. Tying any of the ANY-OUT pins to SNS can increase the resolution of the internal feedback network by lowering the value of R₁. See the *Increasing ANY-OUT Resolution for LILO Conditions* section for additional information.

 $V_{OUT} = V_{NR/SS} \times (1 + R_1 / R_2)$

(5)

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For output voltages greater than 3.95 V, use a traditional adjustable configuration (see the *Adjustable Operation* section).

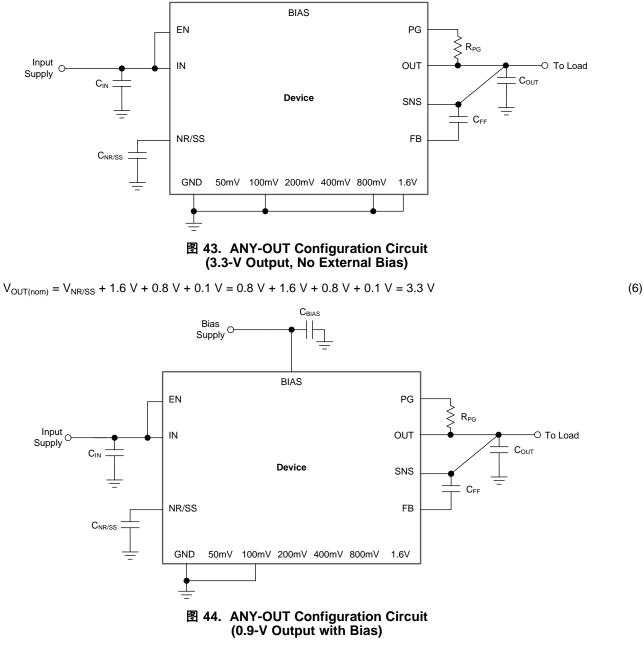
V _{OUT(NOM)} (V)	50mV	100mV	200mV	400mV	800mV	1.6V	V _{OUT(NOM)} (V)	50mV	100mV	200mV	400mV	800mV	1.6V
0.80	Open	Open	Open	Open	Open	Open	2.40	Open	Open	Open	Open	Open	GND
0.85	GND	Open	Open	Open	Open	Open	2.45	GND	Open	Open	Open	Open	GND
0.90	Open	GND	Open	Open	Open	Open	2.50	Open	GND	Open	Open	Open	GND
0.95	GND	GND	Open	Open	Open	Open	2.55	GND	GND	Open	Open	Open	GND
1.00	Open	Open	GND	Open	Open	Open	2.60	Open	Open	GND	Open	Open	GND
1.05	GND	Open	GND	Open	Open	Open	2.65	GND	Open	GND	Open	Open	GND
1.10	Open	GND	GND	Open	Open	Open	2.70	Open	GND	GND	Open	Open	GND
1.15	GND	GND	GND	Open	Open	Open	2.75	GND	GND	GND	Open	Open	GND
1.20	Open	Open	Open	GND	Open	Open	2.80	Open	Open	Open	GND	Open	GND
1.25	GND	Open	Open	GND	Open	Open	2.85	GND	Open	Open	GND	Open	GND
1.30	Open	GND	Open	GND	Open	Open	2.90	Open	GND	Open	GND	Open	GND
1.35	GND	GND	Open	GND	Open	Open	2.95	GND	GND	Open	GND	Open	GND
1.40	Open	Open	GND	GND	Open	Open	3.00	Open	Open	GND	GND	Open	GND
1.45	GND	Open	GND	GND	Open	Open	3.05	GND	Open	GND	GND	Open	GND
1.50	Open	GND	GND	GND	Open	Open	3.10	Open	GND	GND	GND	Open	GND
1.55	GND	GND	GND	GND	Open	Open	3.15	GND	GND	GND	GND	Open	GND
1.60	Open	Open	Open	Open	GND	Open	3.20	Open	Open	Open	Open	GND	GND
1.65	GND	Open	Open	Open	GND	Open	3.25	GND	Open	Open	Open	GND	GND
1.70	Open	GND	Open	Open	GND	Open	3.30	Open	GND	Open	Open	GND	GND
1.75	GND	GND	Open	Open	GND	Open	3.35	GND	GND	Open	Open	GND	GND
1.80	Open	Open	GND	Open	GND	Open	3.40	Open	Open	GND	Open	GND	GND
1.85	GND	Open	GND	Open	GND	Open	3.45	GND	Open	GND	Open	GND	GND
1.90	Open	GND	GND	Open	GND	Open	3.50	Open	GND	GND	Open	GND	GND
1.95	GND	GND	GND	Open	GND	Open	3.55	GND	GND	GND	Open	GND	GND
2.00	Open	Open	Open	GND	GND	Open	3.60	Open	Open	Open	GND	GND	GND
2.05	GND	Open	Open	GND	GND	Open	3.65	GND	Open	Open	GND	GND	GND
2.10	Open	GND	Open	GND	GND	Open	3.70	Open	GND	Open	GND	GND	GND
2.15	GND	GND	Open	GND	GND	Open	3.75	GND	GND	Open	GND	GND	GND
2.20	Open	Open	GND	GND	GND	Open	3.80	Open	Open	GND	GND	GND	GND
2.25	GND	Open	GND	GND	GND	Open	3.85	GND	Open	GND	GND	GND	GND
2.30	Open	GND	GND	GND	GND	Open	3.90	Open	GND	GND	GND	GND	GND
2.35	GND	GND	GND	GND	GND	Open	3.95	GND	GND	GND	GND	GND	GND

表 3. User-Configurable Output Voltage Settings



8.1.8 ANY-OUT Operation

Considering the use of the ANY-OUT internal network (where the unit resistance of 1R is equal to 6.05 k Ω) the output voltage is set by grounding the appropriate control pins, as shown in 图 43. When grounded, all control pins add a specific voltage on top of the internal reference voltage (V_{NR/SS} = 0.8 V). The output voltage can be calculated by 公式 6 and 公式 7. 图 43 and 图 44 show a 0.9-V output voltage, respectively, that provide an example of the circuit usage with and without bias voltage.



 $V_{OUT(nom)} = V_{NR/SS} + 0.1 V = 0.8 V + 0.1 V = 0.9 V$

(7)



8.1.9 Increasing ANY-OUT Resolution for LILO Conditions

As with the adjustable operation, the output voltage is set according to $\Delta \pm 5$, except that R₁ and R₂ are internally integrated and matched for higher accuracy. Tying any of the ANY-OUT pins to SNS can increase the resolution of the internal feedback network by lowering the value of R₁. One of the more useful pin combinations is to tie the 800mV pin to SNS, which reduces the resolution by 50% to 25 mV but limits the range. The new ANY-OUT ranges are 0.8 V to 1.175 V and 1.6 V to 1.975 V. The new additive output voltage levels are listed in $\frac{1}{5}$ 4.

ANY-OUT PROGRAM PINS (Active Low)	ADDITIVE OUTPUT VOLTAGE LEVEL
Pin 5 (50mV)	25 mV
Pin 6 (100mV)	50 mV
Pin 7 (200mV)	100 mV
Pin 9 (400mV)	200 mV
Pin 11 (1.6V)	800 V

表 4. ANY-OUT Programmable Output Voltage with 800mV Tied to SNS

8.1.10 Adjustable Operation

The TPS7A84 can be used either with the internal ANY-OUT network or by using external resistors. Using the ANY-OUT network allows the TPS7A84 to be programmed from 0.8 V to 3.95 V. To extend this output voltage range to 5.0 V, external resistors must be used. This configuration is referred to as the adjustable configuration of the TPS7A84 throughout this document. Regardless whether the internal resistor network or whether external resistors are used, the output voltage is set by two resistors, as shown in 🕅 45. Using the internal resistor ensures a 1% accuracy and minimizes the number of external components.

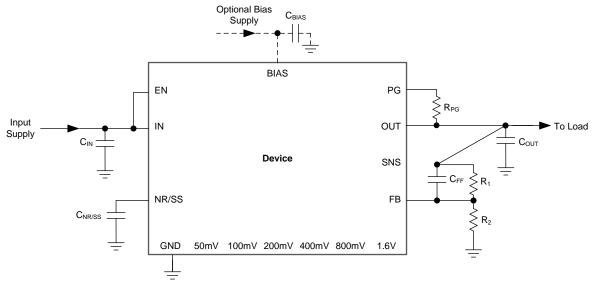


图 45. Adjustable Operation

 R_1 and R_2 can be calculated for any output voltage range using $\Delta \pm 8$. This resistive network must provide a current equal to or greater than 5 μ A for dc accuracy. Using an R_1 of 12.1 k Ω is recommended to optimize the noise and PSRR.

 $V_{OUT} = V_{NR/SS} \times (1 + R_1 / R_2)$

(8)



表 5 shows the resistor combinations required to achieve several common rails using standard 1%-tolerance resistors.

	FEEDBACK RESISTOR VALUES			
V _{OUT(NOM)} (V)	R ₁ (kΩ)	R ₂ (kΩ)		
0.9	12.1	97.6		
1.00	12.1	48.7		
1.10	12.1	32.4		
1.20	12.1	24.3		
1.50	12.1	13.7		
1.80	12.1	9.76		
1.90	12.1	8.87		
2.50	12.1	5.76		
2.85	12.1	4.75		
3.00	12.1	4.42		
3.30	12.1	3.83		
3.60	12.1	3.48		
4.5	12.1	2.61		
5.00	12.1	2.32		

表 5. Recommended I	Feedback-Resistor	Values
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8.1.11 Sequencing Requirements

Supply and enable sequencing is only required when the bias rail is present. The start-up is always monotonic, independent of the sequencing requirements. Under these conditions the following requirements apply:

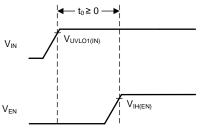


图 46. Sequencing Diagram

Two typical application circuits for implementing the sequencing requirements are detailed in the Sequencing with a Power-Good DC-DC Converter Pin and Sequencing with a Microcontroller (MCU) sections.

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8.1.11.1 Sequencing with a Power-Good DC-DC Converter Pin

When a dc-dc converter is used to power the device and the PG of the dc-dc converter is used to enable the device, pull PGup to V_{IN} , as shown in \mathbb{E} 47.

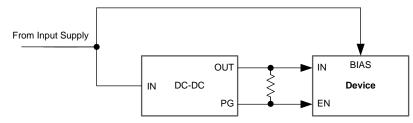


图 47. Sequencing with a DC-DC Converter and PG

8.1.11.2 Sequencing with a Microcontroller (MCU)

If a push-pull output stage is used to provide the enable signal to the device and the enable signal can possibly come before V_{IN} when a bias is present (such as with an MCU), convert the enable signal to an open-drain signal as shown in 🕱 48. Using an open-drain signal ensures that if the signal arrives before V_{IN} , then the enable voltage does not violate the sequencing requirement.

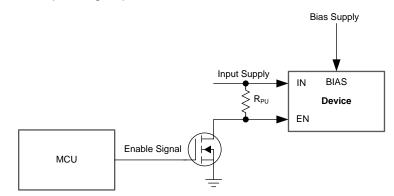


图 48. Push-Pull Enable to Open-Drain Enable

8.1.12 Power-Good Operation

To ensure proper operation of the power-good circuit, the pullup resistor value must be between 10 k Ω and 100 k Ω . The lower limit of 10 k Ω results from the maximum pulldown strength of the power-good transistor, and the upper limit of 100 k Ω results from the maximum leakage current at the power-good node. If the pullup resistor is outside of this range, then the power-good signal may not read a valid digital logic level.

Using a large C_{FF} with a small $C_{NR/SS}$ causes the power-good signal to incorrectly indicate that the output voltage has settled during turn-on. The C_{FF} time constant must be greater than the soft-start time constant to ensure proper operation of the PG during start-up. For a detailed description, see application report *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator*, SBVA042.

The state of PG is only valid when the device operates above the minimum supply voltage. During short UVLO events and at light loads, power-good does not assert because the output voltage is sustained by the output capacitance.



8.1.13 Undervoltage Lockout (UVLO) Operation

The UVLO circuit ensures that the device stays disabled before its input or bias supplies reach the minimum operational voltage range, and ensures that the device shuts down when the input supply or bias supply collapse.

The UVLO circuit has a minimum response time of several microseconds to fully assert. In this time, a downward line transient below approximately 0.8 V causes a partial assertion of UVLO but the UVLO circuit does not have enough stored energy to fully discharge the internal circuits inside of the device. The effect of the downward line transient can be mitigated by either using a larger input capacitor to limit the fall time of the input supply when operating near the minimum V_{IN} , or by using a bias rail near the minimum V_{IN} .

8.1.14 Dropout Voltage (V_{DO})

Generally speaking, the dropout voltage often refers to the minimum voltage difference between the input and output voltage ($V_{DO} = V_{IN} - V_{OUT}$) that is required for regulation. When V_{IN} drops below the required V_{DO} for the given load current, the device functions as a resistive switch and does not regulate output voltage. Dropout voltage is proportional to the output current because the device is operating as a resistive switch; see 22, 23, and 24.

Dropout voltage is affected by the drive strength for the gate of the pass element, which is nonlinear with respect to V_{IN} on this device because of the internal charge pump. The charge pump causes a higher dropout voltage at lower input voltages when a bias rail is not used, as illustrated in 🕱 20.

For this device, dropout voltage increases exponentially when the input voltage nears its maximum operating voltage because the charge pump is internally clamped to 8.0 V; see 🛽 20 and 🔄 21.

8.1.15 Behavior when Transitioning from Dropout into Regulation

When the device is in a dropout state (not during start-up), the pass-FET is driven as hard as possible when the control loop is out of balance. During the normal time required for the device to regain regulation, $V_{IN} \ge V_{OUT(nom)} + V_{DO}$, V_{OUT} overshoots if the input voltage slew rate is 0.1 V/µs or faster. The same overshoot can also occur if a load transient causes the device to enter dropout because the error amplifier has a limited response time in recovering from the load dump event. A small dc load can help mitigate this situation.

8.1.16 Load Transient Response

The load-step transient response is the output voltage response by the LDO to a step in load current, whereby output voltage regulation is maintained; see \mathbb{R} 16. There are two key transitions during a load transient response: the transition from a light to a heavy load and the transition from a heavy to a light load.

During transitions from a light load to a heavy load, the:

- Initial voltage dip is a result of the depletion of the output capacitor charge and parasitic impedance to the output capacitor
- Recovery from the dip results from the LDO increasing its sourcing current, and leads to output voltage regulation

During transitions from a heavy load to a light load, the:

- Initial voltage rise results from the LDO sourcing a large current, and leads to the output capacitor charge to increase
- Recovery from the rise results from the LDO decreasing its sourcing current in combination with the load discharging the output capacitor

Transitions between current levels changes the internal power dissipation because the TPS7A84 is a highcurrent device. The change in power dissipation changes the die temperature during these transitions, and leads to a slightly different voltage level. This different output voltage level shows up in the various load transient responses; see 🛚 16.

A larger output capacitance reduces the peaks during a load transient but slows down the response time of the device. A larger dc load also reduces the peaks because the amplitude of the transition is lowered and a higher current discharge path is provided for the output capacitor; see 🛽 18.

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8.1.17 Negative Biased Output

The device does not start or operate as expected if the output voltage is pulled below ground. This issue commonly occurs when powering a split-rail system where the negative rail is established before the device is enabled. Several application solutions are:

- Enable the device before the negative regulator and disable the device after the negative regulator.
- Delaying the EN voltage with respect to the IN voltage allows the internal pulldown resistor to discharge any voltage at OUT. If the discharge circuit is not strong enough to keep the output voltage at ground, then use an external pulldown resistor.
- Place a zener diode from IN to OUT to provide a small positive dc bias on the output when the input is supplied to the device, as shown in 图 49.

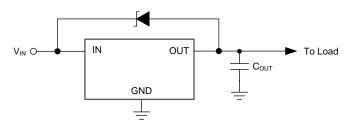


图 49. Zener Diode Placed from IN to OUT

• Use a PFET to isolate the output of the device from the load causing the negative bias when the device is off, as shown in 图 50.

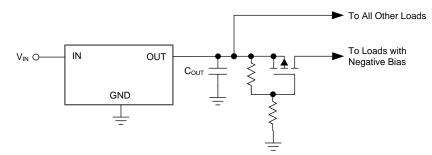


图 50. PFET to Isolate the Output from the Load

8.1.18 Power Dissipation (P_D)

Circuit reliability demands that proper consideration be given to device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must be as free as possible of other heat-generating devices that cause added thermal stresses.

As a first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. P_D can be calculated using $\Delta \pm 9$:

$$\mathsf{P}_{\mathsf{D}} = (\mathsf{V}_{\mathsf{OUT}} - \mathsf{V}_{\mathsf{IN}}) \times \mathsf{I}_{\mathsf{OUT}}$$

(10)

An important note is that power dissipation can be minimized, and thus greater efficiency achieved, by proper selection of the system voltage rails. Proper selection allows the minimum input-to-output voltage differential to be obtained. The low dropout of the TPS7A84 allows for maximum efficiency across a wide range of output voltages.

The primary heat conduction path for the package is through the thermal pad to the PCB. Solder the thermal pad to a copper pad area under the device. This pad area contains an array of plated vias that conduct heat to any inner plane areas or to a bottom-side copper plane.

The maximum power dissipation determines the maximum allowable junction temperature (T_J) for the device. Power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance (θ_{JA}) of the combined PCB and device package and the temperature of the ambient air (T_A) , according to $\Delta \vec{x}$ 10.

$$= T_A + (\theta_{JA} \times P_D)$$

T.



Unfortunately, this thermal resistance (θ_{JA}) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The θ_{JA} recorded in the *Electrical Characteristics* table is determined by the JEDEC standard, PCB, and copper-spreading area, and is only used as a relative measure of package thermal performance. Note that for a well-designed thermal layout, θ_{JA} is actually the sum of the VQFN package junction-to-case (bottom) thermal resistance (θ_{JCbot}) plus the thermal resistance contribution by the PCB copper.

8.1.19 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the LDO when in-circuit on a typical PCB board application. These metrics are not strictly speaking thermal resistances, but rather offer practical and relative means of estimating junction temperatures. These psi metrics are determined to be significantly independent of the copper-spreading area. The key thermal metrics (Ψ_{JT} and Ψ_{JB}) are given in the *Electrical Characteristics* table and are used in accordance with Δr 11.

$$\begin{split} \Psi_{\mathsf{JT}} &: \mathsf{T}_{\mathsf{J}} = \mathsf{T}_{\mathsf{T}} + \Psi_{\mathsf{JT}} \times \mathsf{P}_{\mathsf{D}} \\ \Psi_{\mathsf{JB}} &: \mathsf{T}_{\mathsf{J}} = \mathsf{T}_{\mathsf{B}} + \Psi_{\mathsf{JB}} \times \mathsf{P}_{\mathsf{D}} \end{split}$$

where:

- P_D is the power dissipated as explained in $\Delta \pm 9$
- T_T is the temperature at the center-top of the device package, and
- T_B is the PCB surface temperature measured 1 mm from the device package and centered on the package edge (11)

8.2 Typical Applications

8.2.1 Low-Input, Low-Output (LILO) Voltage Conditions

This section discusses the implementation of the TPS7A84 using the ANY-OUT configuration to regulate a 3.0-A load requiring good PSRR at high frequency with low-noise at 0.9 V using a 1.3-V input voltage and a 5.0-V bias supply. The schematic for this typical application circuit is provided in 图 51.

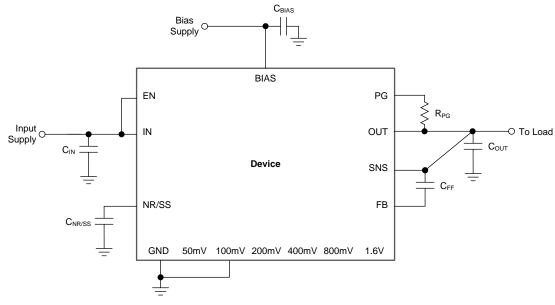


图 51. Typical Application

8.2.1.1 Design Requirements

For this design example, use the parameters listed in $\frac{1}{5}$ 6 as the input parameters.

A 0. Design Farameters						
PARAMETER	DESIGN REQUIREMENT					
Input voltage	1.3 V, ±3%, provided by the dc-dc converter switching at 500 kHz					
Bias voltage	5.0 V, ±5%					
Output voltage	0.9 V, ±1%					
Output current	3.0 A (maximum), 100 mA (minimum)					
RMS noise, 10 Hz to 100 kHz	< 10 µV _{RMS}					
PSRR at 500 kHz	> 40 dB					

< 25 ms

表 6. Design Parameters

8.2.1.2 Detailed Design Procedure

Start-up time

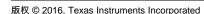
At 3.0 A, the dropout of the TPS7A84 has 180-mV maximum dropout over temperature, thus a 400-mV headroom is sufficient for operation over both input and output voltage accuracy. The bias rail is provided for better performance for the LILO conditions. The PSRR is greater than 40 dB in these conditions, as per 😤 1. Noise is less than 10 μ V_{RMS}, as per 😤 8.

The ANY-OUT internal resistor network is also used for maximum accuracy.

To achieve 0.9 V on the output, the 100mV pin is grounded. The voltage value of 100 mV is added to the 0.8-V internal reference voltage for $V_{OUT(nom)}$ equal to 0.9 V, as described in $\Delta \pm 12$.

V_{OUT(nom)} = V_{NR/SS} + 0.1 V = 0.8 V + 0.1 V = 0.9 V

(12)





VEN

25

Time (ms)

图 53. Output Start-Up Response

30 35 40 45 50

 V_{OUT} , $C_{NR/SS} = 0 \text{ nF}$

V_{OUT}, C_{NR/SS} = 10 nF

 V_{OUT} , $C_{NR/SS} = 47 \text{ nF}$

 V_{OUT} , $C_{NR/SS} = 100 \text{ nF}$

Input and output capacitors are selected in accordance with the Recommended Capacitor Types section. Ceramic capacitances of 47 µF for the input and one 47-µF capacitor in parallel with two 10-µF capacitors for the output are selected.

To satisfy the required start-up time and still maintain low-noise performance, a 100-nF C_{NR/SS} is selected. This value is calculated with 公式 13.

 $t_{SS} = (V_{NR/SS} \times C_{NR/SS}) / I_{NR/SS}$

At the 3.0-A maximum load, the internal power dissipation is 1.2 W and corresponds to a 42.48°C junction temperature rise for the RGR package on a standard JEDEC board. With an 55°C maximum ambient temperature, the junction temperature is at 97.5°C. To further minimize noise, a feed-forward capacitance (C_{FF}) of 10 nF is selected.

1.2

1

0.8

0.4

0.2

0

0

5

10 15 20

-02

/oltage (V) 0.6

100

75

25

0

-25

-50

-75

-125

-150

ð 50

Coupled

Output Voltage

Ê -100

IOUT

VOUT, AC

90 100

8.2.1.3 Application Curves



50

Time (µs)

60 70 80

图 52. Output Load Transient Response

This section discusses the implementation of the TPS7A84 using an adjustable feedback network to regulate a 3-A load requiring good PSRR at high frequency with low-noise at an output voltage of 5.0 V. The schematic for this typical application circuit is provided in 8 54.

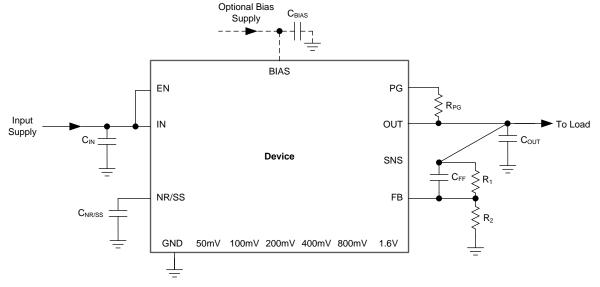


图 54. Typical Application



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10

9

8

7

6

5

4

3

2

1

0

0 10 20 30 40

Output Current (A)

(13)

31

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(14)

8.2.2.1 Design Requirements

For this design example, use the parameters listed in $\frac{1}{5}$ 6 as the input parameters.

PARAMETER	DESIGN REQUIREMENT			
Input voltage	5.50 V, \pm 1%, provided by the dc-dc converter switching at 500 kHz			
Bias voltage	Not used because $V_{OUT} \ge 2.20 V$			
Output voltage	5.0 V, ±1%			
Output current	3.0 A (maximum), 10 mA (minimum)			
RMS noise, 10 Hz to 100 kHz	< 10 μV _{RMS}			
PSRR at 500 kHz	> 40 dB			
Start-up time	< 25 ms			

表 7. Design Parameters

8.2.2.2 Detailed Design Procedure

At 3.0 A and 5.0 V_{OUT} , the dropout of the TPS7A84 has a 340-mV maximum dropout over temperature, thus a 500-mV headroom is sufficient for operation over both input and output voltage accuracy. At full load and high temperature on some devices, the TPS7A84 can enter dropout if both the input and output supply are beyond the edges of their accuracy specification.

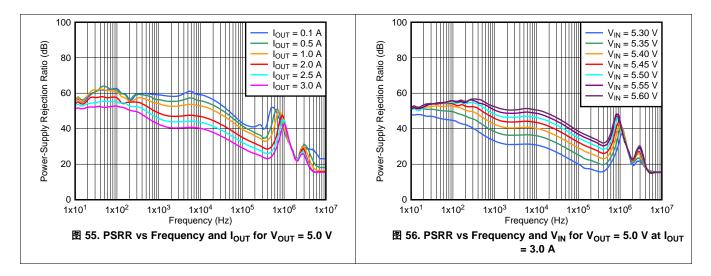
For a 5.0-V output. use external adjustable resistors. See the resistor values in listed 表 5 for choosing resistors for a 5.0-V output.

Input and output capacitors are selected in accordance with the *Recommended Capacitor Types* section. Ceramic capacitances of 47 μ F for the input and one 47- μ F capacitor in parallel with two 10- μ F capacitors for the output are selected.

To satisfy the required start-up time and still maintain low noise performance, a 100-nF $C_{NR/SS}$ is selected. This value is calculated with $\Delta \pm$ 13.

$$t_{SS} = (V_{NR/SS} \times C_{NR/SS}) / I_{NR/SS}$$

At the 3.0-A maximum load, the internal power dissipation is 1.5 W and corresponds to a 53.1°C junction temperature rise for the RGR package on a standard JEDEC board. With an 55°C maximum ambient temperature, the junction temperature is at 108.1°C. To further minimize noise, a feed-forward capacitance (C_{FF}) of 10 nF is selected.



8.2.2.3 Application Curves



9 Power-Supply Recommendations

The TPS7A84 is designed to operate from an input voltage supply range between 1.1 V and 6.5 V. If the input supply is less than 1.4 V, then a bias rail of at least 3.0 V must be used. The input voltage range provides adequate headroom in order for the device to have a regulated output. This input supply must be well regulated. If the input supply is noisy, additional input capacitors with low ESR can help improve output noise performance.

10 Layout

10.1 Layout Guidelines

10.1.1 Board Layout

For best overall performance, place all circuit components on the same side of the circuit board and as near as practical to the respective LDO pin connections. Place ground return connections to the input and output capacitor, and to the LDO ground pin as close to each other as possible, connected by a wide, component-side, copper surface. The use of vias and long traces to the input and output capacitors is strongly discouraged and negatively affects system performance. The grounding and layout scheme illustrated in 😤 57 minimizes inductive parasitics, and thereby reduces load-current transients, minimizes noise, and increases circuit stability.

A ground reference plane is also recommended and is either embedded in the PCB itself or located on the bottom side of the PCB opposite the components. This reference plane serves to assure accuracy of the output voltage, shield noise, and behaves similar to a thermal plane to spread (or sink) heat from the LDO device when connected to the thermal pad. In most applications, this ground plane is necessary to meet thermal requirements.

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NSTRUMENTS

ÈXAS

10.2 Layout Example

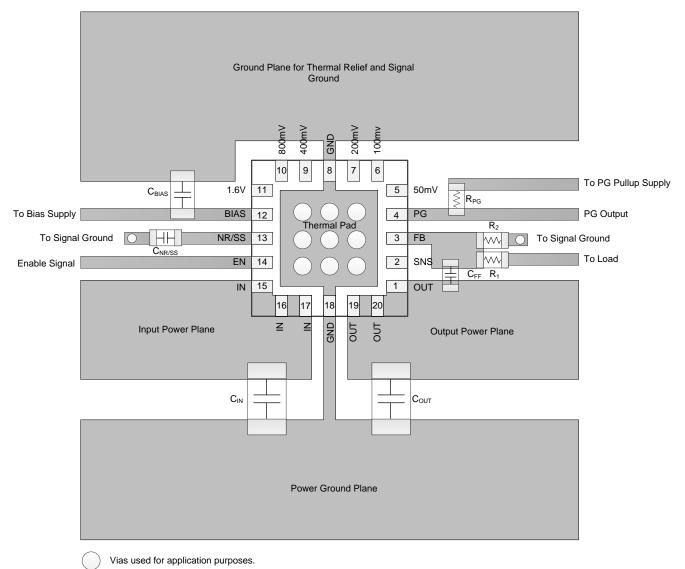


图 57. Example Layout



11 器件和文档支持

- 11.1 器件支持
- 11.1.1 开发支持

11.1.1.1 评估模块

评估模块 (EVM) 可与 TPS7A84 配套使用,帮助评估初始电路性能。有关此固定装置的相关摘要信息,请参见表8。

表 8. 设计套件与评估模块

名称	文献编号
TPS7A8300EVM-209 评估模块	SLVU919
TPS7A8300EVM-579 评估模块	SBVU021

您可以在德州仪器 (TI) 网站上的 TPS7A84 产品文件夹中获取 EVM。

11.1.1.2 Spice 模型

分析模拟电路和系统的性能时,使用 SPICE 模型对电路性能进行计算机仿真非常有用。您可以从 TPS7A84 产品 文件夹中的仿真模型下获取 TPS7A84 的 SPICE 模型。

11.1.2 器件命名规则

表 9. 订购信息(1)

产品	说明
TPS7A84 YYYZ	YYY 为封装标识符。 Z 为封装数量。

(1) 欲获得最新的封装和订货信息,请参阅本文档末尾的封装选项附录,或者访问 www.ti.com 查看器件产品文件夹。

11.2 文档支持

11.2.1 相关文档

相关文档如下:

- TPS3702 数据表, SBVS251
- TPS7A8300EVM-209 评估模块, SLVU919
- TPS7A8300EVM-579 评估模块, SBVU021
- 使用前馈电容器和低压降稳压器的优缺点, SBVA042

11.3 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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ESD 的损坏小至导致微小的性能降级,大至整个器件故障。精密的集成电路可能更容易受到损坏,这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

11.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对 本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本,请查阅左侧的导航栏。

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10-Dec-2020

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS7A8400RGRR	ACTIVE	VQFN	RGR	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	11CI	Samples
TPS7A8400RGRT	ACTIVE	VQFN	RGR	20	250	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	11CI	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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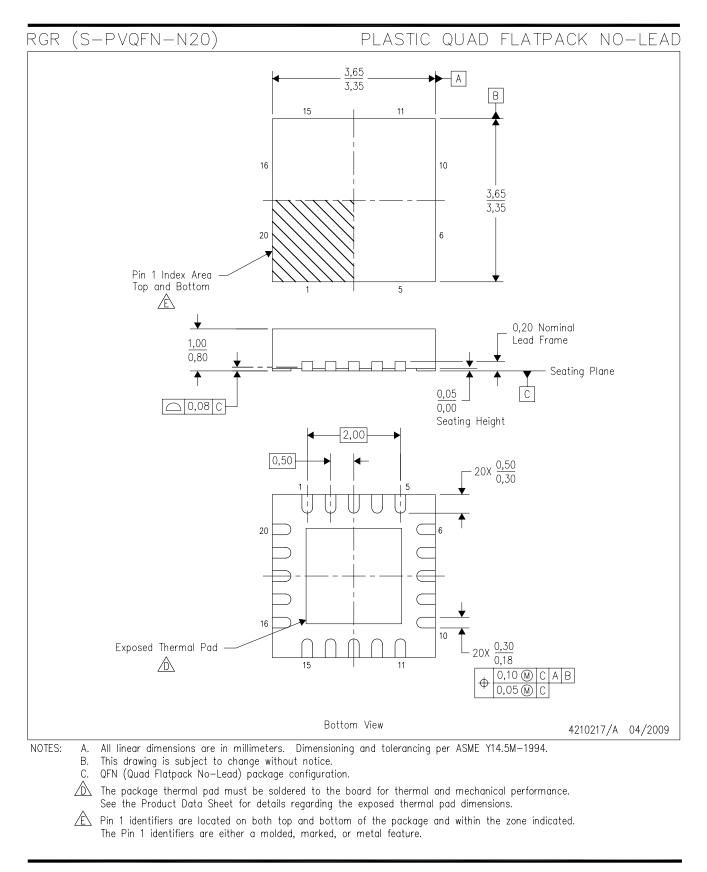


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PACKAGE OPTION ADDENDUM

10-Dec-2020

MECHANICAL DATA





RGR (S-PVQFN-N20)

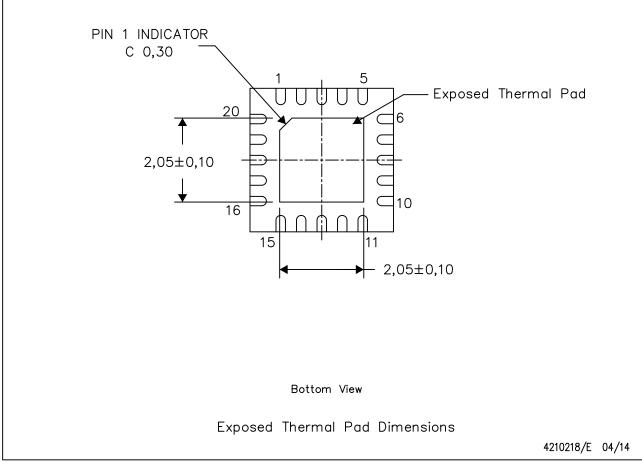
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

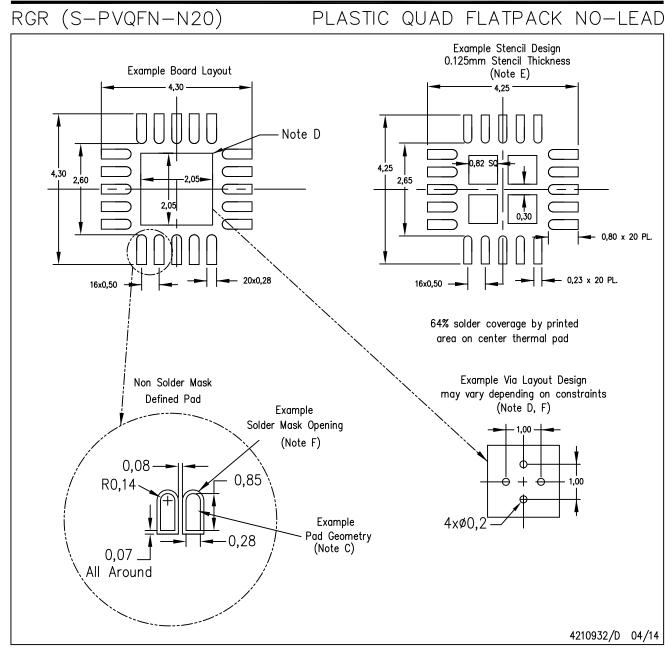
For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.









NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



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